



DMP3028LFDEQ

## **30V P-CHANNEL ENHANCEMENT MODE MOSFET**

## **Product Summary**

BV <sub>DSS</sub>	Rds(on) max	I <sub>D MAX</sub> T <sub>A</sub> = +25°С
-30V	25mΩ @ V <sub>GS</sub> = -10V	-6.8A
-307	38mΩ @ V <sub>GS</sub> = -4.5V	-5.0A

## Features

- Low Input Capacitance
- Low On-Resistance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- The DMP3028LFDEQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

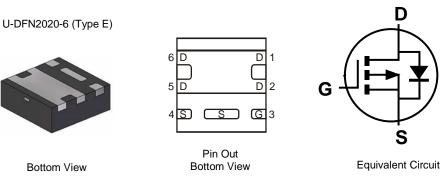
# **Description and Applications**

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP, and is ideal for use in:

- DC-DC Converters
- Power Management Functions
- Load Switch

## **Mechanical Data**

- Case: U-DFN2020-6
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Lead-Frame. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.0065 grams (Approximate)



## Ordering Information (Note 4)

Part Number	Case	Packaging
DMP3028LFDEQ-7	U-DFN2020-6 (Type E)	3,000/Tape & Reel
DMP3028LFDEQ-13	U-DFN2020-6 (Type E)	10,000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



# **Marking Information**

#### Site 1



 $\begin{array}{l} \mathsf{PX} = \mathsf{Product} \ \mathsf{Type} \ \mathsf{Marking} \ \mathsf{Code} \\ \mathsf{YM} = \mathsf{Date} \ \mathsf{Code} \ \mathsf{Marking} \\ \mathsf{Y} = \mathsf{Year} \ (\mathsf{ex:} \ \mathsf{H} = 2020) \\ \mathsf{M} = \mathsf{Month} \ (\mathsf{ex:} \ 9 = \mathsf{September}) \end{array}$ 

## Date Code Key

Year	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	Н		J	K	L	М	N	0	Р	R	S	Т
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Site 2



PX= Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 0 = 2020) W = Week (ex: a = Week 27; z Represents Week 52 and 53) X = Internal Code (ex: U = Monday)

## Date Code Key

Year	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	0	1	2	3	4	5	6	7	8	9	0	1
Week	1-26				27	' <b>-</b> 52		53				
Code	A-Z				a-z				Z			
Internal Code	Su	ın	Mor	1	Tue	1	Wed	Thu	I	Fri		Sat
Code	1		U		V		W	Х		Y		Z



# Maximum Ratings (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit			
Drain-Source Voltage		V <sub>DSS</sub>	-30	V		
Gate-Source Voltage			V <sub>GSS</sub>	±20	V	
Continuous Drain Current (Note 6) \/ 40\/	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	-6.8 -5.3	А	
Continuous Drain Current (Note 6) V <sub>GS</sub> = -10V	ID	-8.2 -6.6	A			
Maximum Body Diode Forward Current (Note 6)		Is	-2.5	А		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	)		I <sub>DM</sub>	-40	А	

# Thermal Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Tatal Dawar Dissinction (Nata E)	T <sub>A</sub> = +25°C	D	0.66	W
Total Power Dissipation (Note 5)	T <sub>A</sub> = +70°C	PD	0.42	vv
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{ extsf{ heta}JA}$	189	°C/W
Total Power Dissipation (Note 6)	T <sub>A</sub> = +25°C	Р	2.03	W
Total Power Dissipation (Note 6)	T <sub>A</sub> = +70°C	PD	1.3	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{ extsf{ heta}JA}$	61	°C/W
Thermal Resistance, Junction to Case (Note 6)	R <sub>θ</sub> JC	9.3	C/W	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

# Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

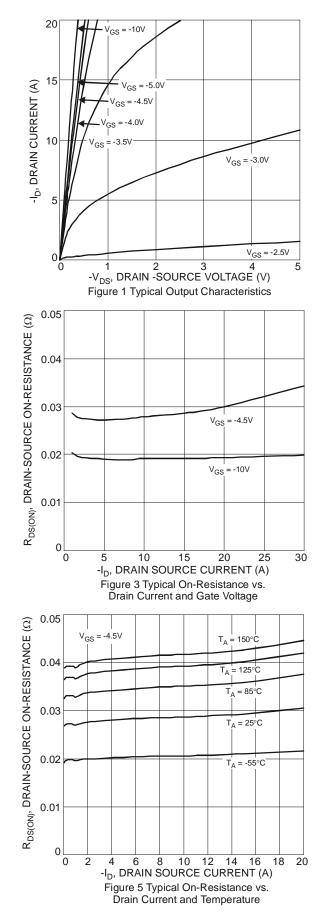
				-		
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)				-		
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-30	—	—	V	$V_{GS} = 0V, I_D = -250 \mu A$
Zero Gate Voltage Drain Current	I <sub>DSS</sub>			-1	μA	$V_{DS} = -30V, V_{GS} = 0V$
Gate-Source Leakage	I <sub>GSS</sub>			±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-1.2	—	-2.4	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$
Static Drain-Source On-Resistance	<b>D</b>		20	25	mΩ	$V_{GS} = -10V, I_D = -7A$
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>		29	38	11122	$V_{GS} = -4.5V, I_D = -6.2A$
Diode Forward Voltage	$V_{SD}$		-0.7	-1.2	V	$V_{GS} = 0V, I_{S} = -2.1A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss		1241	1860		
Output Capacitance	Coss		147	220	pF	$V_{DS} = -15V, V_{GS} = 0V$ f = 1.0MHz
Reverse Transfer Capacitance	C <sub>rss</sub>		110	165		
Gate Resistance	R <sub>G</sub>		15	30	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge (V <sub>GS</sub> = -10V)	Qg		22	33		
Total Gate Charge (V <sub>GS</sub> = -4.5V)	Qg		10.9	17	nC	
Gate-Source Charge	Qgs	_	3.5	6	nc	$V_{DS} = -15V, I_D = -7A$
Gate-Drain Charge	Q <sub>gd</sub>	_	4.7	8		
Turn-On Delay Time	t <sub>D(ON)</sub>	_	9.7	15		
Turn-On Rise Time	t <sub>R</sub>	_	17.1	26	20	$V_{GS}$ = -10V, $V_{DD}$ = -15V, $R_{GEN}$ = 6 $\Omega$ ,
Turn-Off Delay Time	t <sub>D(OFF)</sub>		60.5	91	ns	I <sub>D</sub> = -7A
Turn-Off Fall Time	t <sub>F</sub>	_	40.4	61		

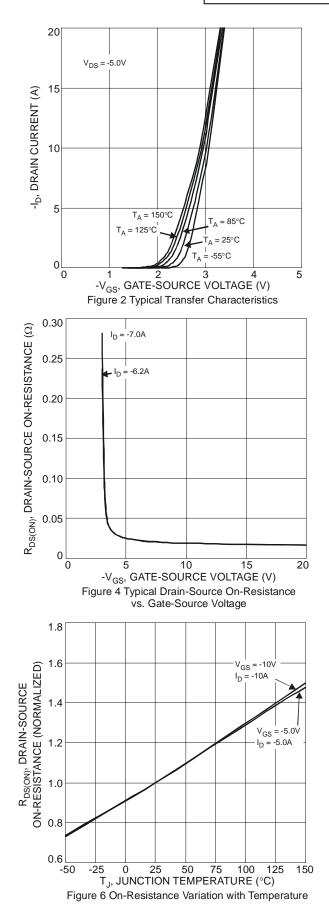
 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to product testing.

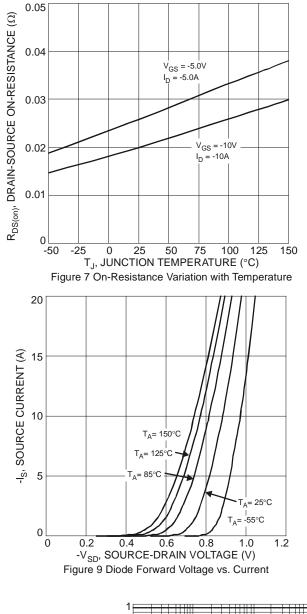


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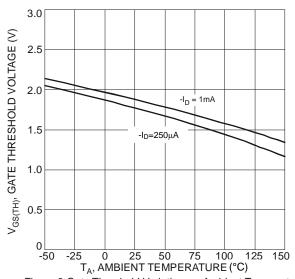
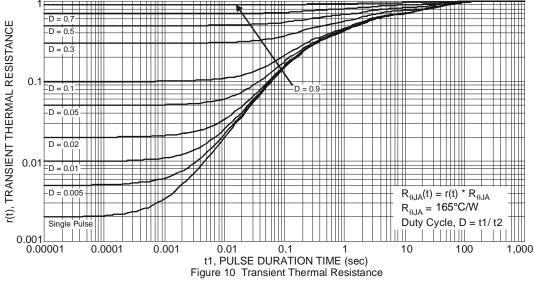


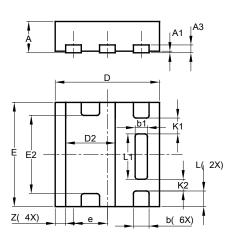
Figure 8 Gate Threshold Variation vs. Ambient Temperature





# **Package Outline Dimensions**

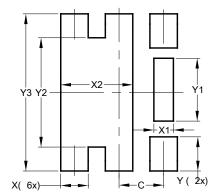
Please see http://www.diodes.com/package-outlines.html for the latest version.



	U-DFN2020-6 Type E							
Dim	n Min Max Typ							
Α	0.57	0.63	0.60					
A1	0	0.05	0.03					
A3	-	-	0.15					
b	0.25	0.35	0.30					
b1	0.185	0.185 0.285	0.235					
D	1.95	2.05	2.00					
D2	0.85	1.05	0.95					
E	1.95	2.05	2.00					
E2	1.40	1.60	1.50					
e	-	-	0.65					
L	0.25	0.35	0.30					
L1	0.82	0.92	0.87					
K1	_	_	0.305					
K2	-	_	0.225					
Z	_	_	0.20					
All	Dimen	isions i	n mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



## U-DFN2020-6 (Type E)

U-DFN2020-6 (Type E)

Dimensions	Value (in mm)
С	0.650
Х	0.400
X1	0.285
X2	1.050
Y	0.500
Y1	0.920
Y2	1.600
Y3	2.300

DMP3028LFDEQ Document number: DS42703 Rev. 1 - 2



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